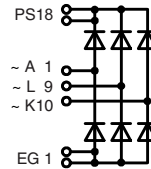


Three Phase Rectifier Bridge with Fast Recovery Epitaxial Diodes (FRED) in ECO-PAC 2

Preliminary data sheet

V_{RSM} V	V_{RRM} V	Typ
1300	1200	VUE 130-12NO7



Pin arrangement see outlines

Symbol	Conditions	Maximum Ratings
I_{dAV}^*	$T_C = 70^\circ\text{C}$, module	130 A
I_{dAVM}		90 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine
I^2t	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine
	$T_{VJ} = T_{VJM}$ $V_R = 0$	$t = 10\text{ ms}$ (50 Hz), sine $t = 8.3\text{ ms}$ (60 Hz), sine
T_{VJ}		$-40...+150^\circ\text{C}$
T_{VJM}		150°C
T_{stg}		$-40...+125^\circ\text{C}$
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1\text{ mA}$	$t = 1\text{ min}$ $t = 1\text{ s}$
		3000 V~ 3600 V~
M_d Weight	Mounting torque (M4) typ.	1.5-2/14-18 Nm/lb.in. 24 g

Features

- Package with DCB ceramic base plate in low profile
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

Applications

- Supplies for DC power equipment
- Input and output rectifiers for high frequency
- Battery DC power supplies
- Field supply for DC motors

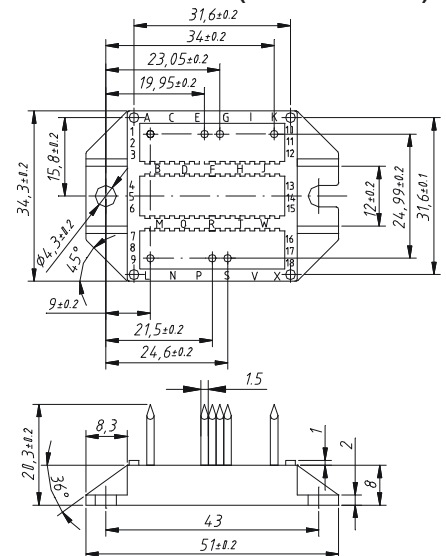
Advantages

- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight
- Low noise switching

Symbol	Conditions	Characteristic Values
		typ. max.
I_R	$V_R = V_{RRM}$ $V_R = V_{RRM}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = T_{VJM}$
		1 mA 2.5 mA
V_F	$I_F = 60\text{ A}$	$T_{VJ} = 25^\circ\text{C}$
		2.7 V
V_{T0}	for power-loss calculations only	1.07 V
r_T		8.2 mΩ
R_{thJC}	per diode; DC current	0.8 K/W
R_{thCH}	per diode, DC current, typ.	0.2 K/W
I_{RM}	$I_F = 130\text{ A}$, $-diF/dt = 100\text{ A}/\mu\text{s}$ $V_R = 100\text{ V}$, $T_{VJ} = 100^\circ\text{C}$	7 15 A
t_{rr}	$I_F = 1\text{ A}$; $-di/dt = 300\text{ A}/\mu\text{s}$; $V_R = 30\text{ V}$, $T_{VJ} = 25^\circ\text{C}$	40 ns
a	Max. allowable acceleration	50 m/s ²
d_s	creeping distance on surface (pin to heatsink)	11.2 mm
d_A	strike distance in air (pin to heatsink)	9.7 mm

Data according to IEC 60747 refer to a single diode unless otherwise stated
* for resistive load at bridge output.

Dimensions in mm (1 mm = 0.0394")



IXYS reserves the right to change limits, test conditions and dimensions.

© 2002 IXYS All rights reserved

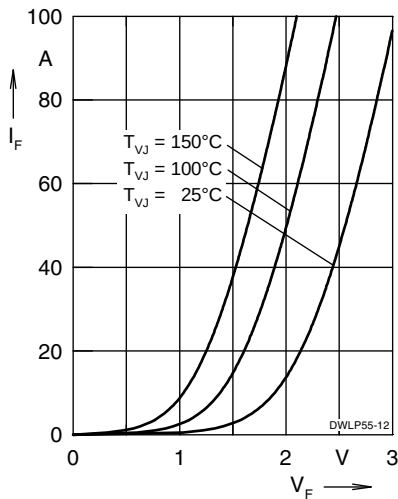


Fig. 1 Forward current I_F versus V_F

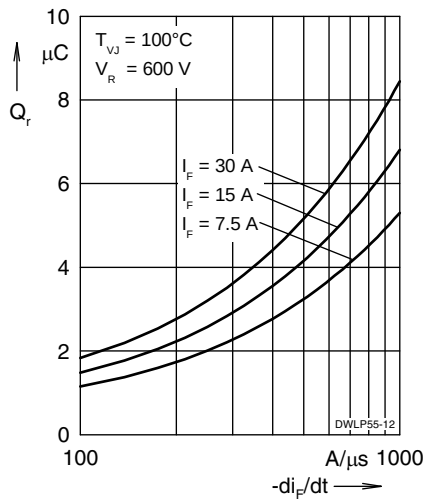


Fig. 2 Reverse recovery charge Q_r versus $-di_F/dt$

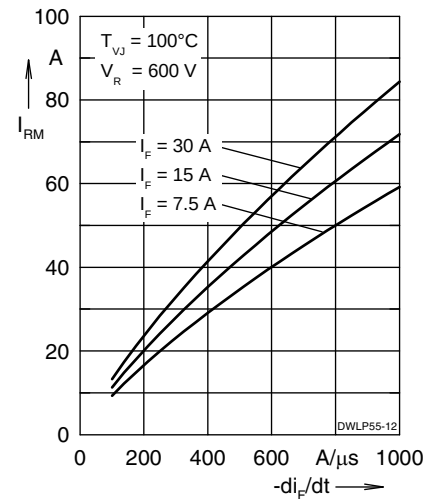


Fig. 3 Peak reverse current I_{RM} versus $-di_F/dt$

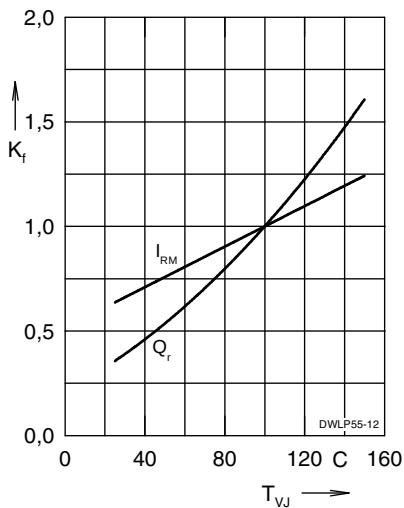


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

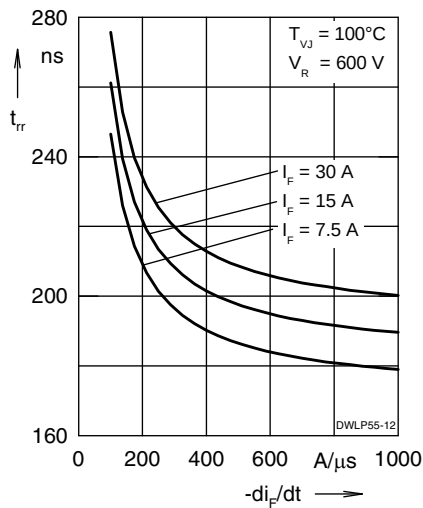


Fig. 5 Recovery time t_{rr} versus $-di_F/dt$

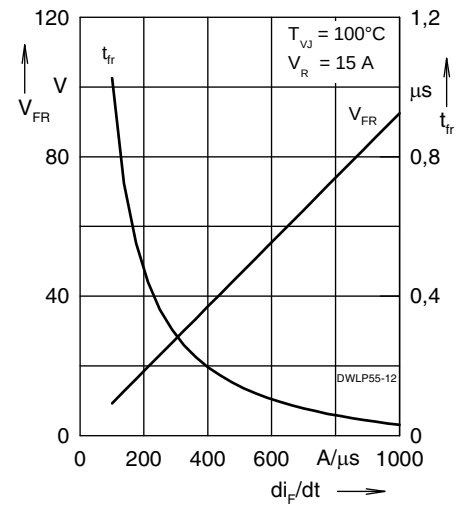


Fig. 6 Peak forward voltage V_{FR} and t_{fr} versus di_F/dt

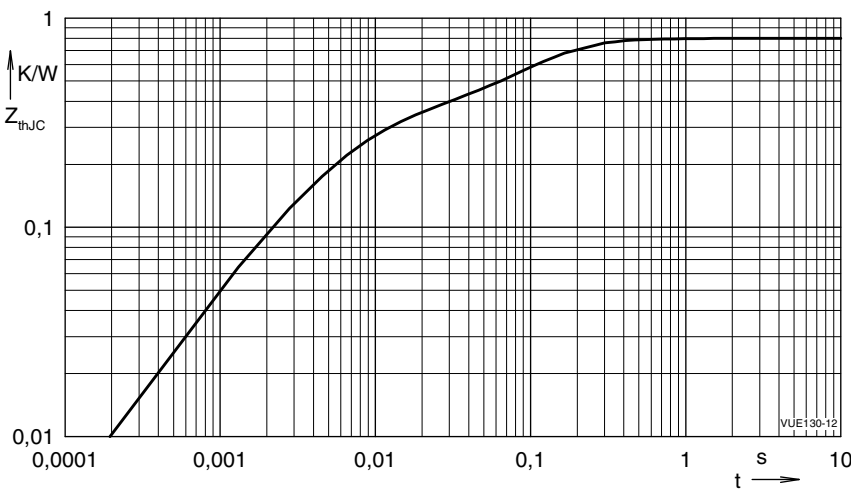


Fig. 7 Typical transient thermal resistance junction to case

NOTE: Fig. 2 to Fig. 6 shows typical values

IXYS reserves the right to change limits, test conditions and dimensions.

© 2002 IXYS All rights reserved